



BAP51LX

Silicon PIN diode

Rev. 3 — 26 November 2018

Product data sheet

1 Product profile

1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

1.2 Features and benefits

- High-speed switching for RF signals
- Low diode capacitance
- Low forward resistance
- Very low series inductance
- For applications up to 3 GHz
- AEC-Q101 qualified

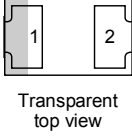

1.3 Applications

- RF attenuators and switches



2 Pinning information

Table 1. Discrete pinning

| Pin | Description | | Simplified outline | Symbol |
|-----|-------------|-----|---|---|
| 1 | cathode | [1] |  <p>Transparent top view</p> |  sym006 |
| 2 | anode | | | |

[1] The marking bar indicates the cathode.

3 Ordering information

Table 2. Ordering information

| Type number | Package | | |
|-------------|------------|--|---------|
| | Name | Description | Version |
| BAP51LX | DFN1006D-2 | leadless ultra small plastic package; 2 terminals; body 1 × 0.6 × 0.4 mm | SOD882D |

4 Marking code

Table 3. Marking code

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| BAP51LX | 1001 0100 |

[1] For SOD882D binary marking code description, see [Figure 1](#).

4.1 Binary marking code description

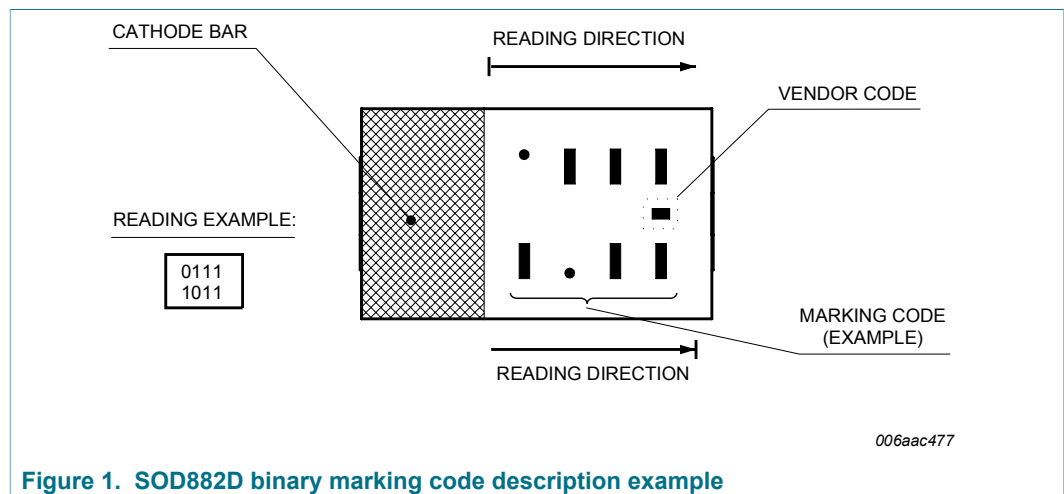


Figure 1. SOD882D binary marking code description example

5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|----------------------------|-----|------|------|
| V_R | reverse voltage | | - | 60 | V |
| I_F | forward current | | - | 100 | mA |
| P_{tot} | total power dissipation | $T_{sp} \leq 90\text{ °C}$ | - | 140 | mW |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | | -65 | +150 | °C |

6 Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Typ | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | 66 | K/W |

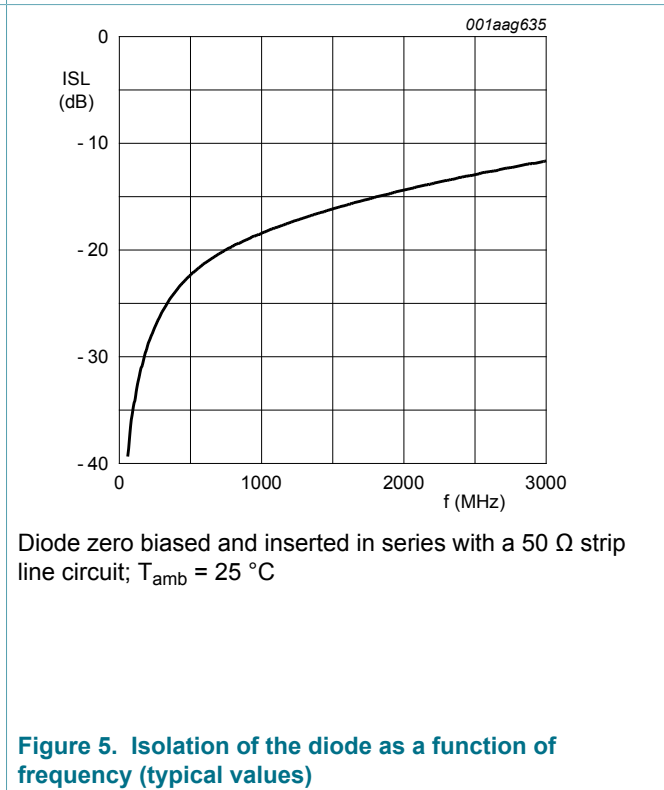
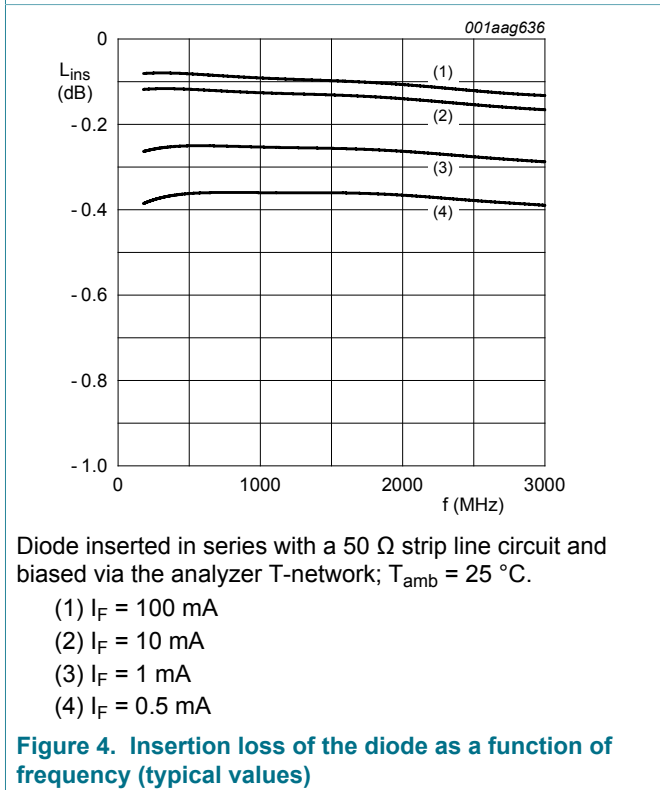
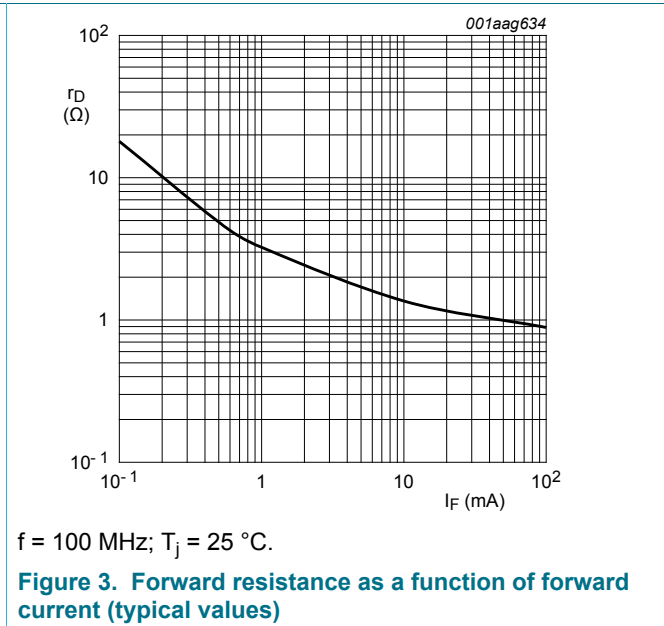
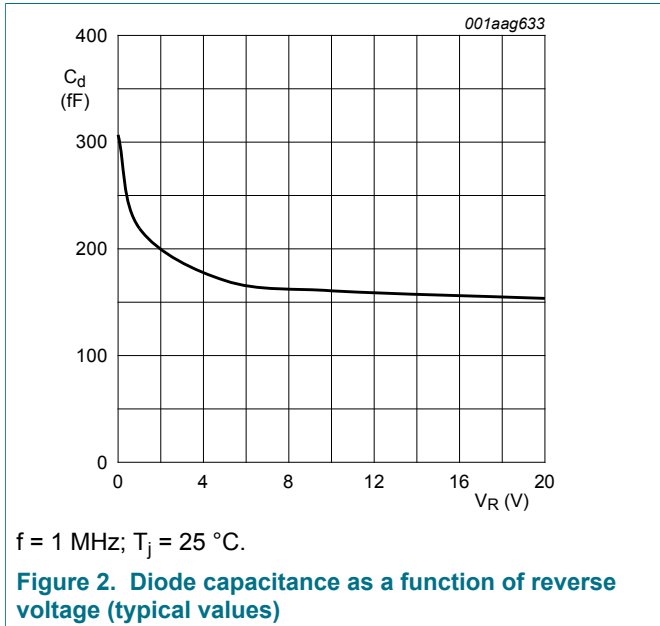
7 Characteristics

Table 6. Characteristics
 $T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--------------|--------------------------|--|-----|------|------|----------|--|
| V_F | forward voltage | $I_F = 50\text{ mA}$ | - | 0.95 | 1.1 | V | |
| I_R | reverse current | $V_R = 50\text{ V}$ | - | - | 100 | nA | |
| C_d | diode capacitance | f = 1 MHz (see Figure 2) | | | | | |
| | | $V_R = 0\text{ V}$ | - | 0.30 | - | pF | |
| | | $V_R = 1\text{ V}$ | - | 0.22 | 0.40 | pF | |
| | | $V_R = 5\text{ V}$ | - | 0.17 | 0.30 | pF | |
| r_D | diode forward resistance | f = 100 MHz (see Figure 3) | | | | | |
| | | $I_F = 0.5\text{ mA}$ | - | 4.9 | 9 | Ω | |
| | | $I_F = 1\text{ mA}$ | - | 3.2 | 6.5 | Ω | |
| | | $I_F = 10\text{ mA}$ | - | 1.4 | 2.5 | Ω | |
| ISL | isolation | $V_R = 0\text{ V}$ (see Figure 5) | | | | | |
| | | f = 900 MHz | - | 19 | - | dB | |
| | | f = 1800 MHz | - | 15 | - | dB | |
| | | f = 2450 MHz | - | 13 | - | dB | |
| L_{ins} | insertion loss | (See Figure 4) | | | | | |
| | | $I_F = 0.5\text{ mA}$ | | | | | |
| | | f = 900 MHz | - | 0.36 | - | dB | |
| | | f = 1800 MHz | - | 0.36 | - | dB | |
| | | f = 2450 MHz | - | 0.38 | - | dB | |
| | | $I_F = 1\text{ mA}$ | | | | | |
| | | f = 900 MHz | - | 0.25 | - | dB | |
| | | f = 1800 MHz | - | 0.26 | - | dB | |
| | | f = 2450 MHz | - | 0.27 | - | dB | |
| | | $I_F = 10\text{ mA}$ | | | | | |
| | | f = 900 MHz | - | 0.12 | - | dB | |
| | | f = 1800 MHz | - | 0.14 | - | dB | |
| | | f = 2450 MHz | - | 0.15 | - | dB | |
| | | $I_F = 100\text{ mA}$ | | | | | |
| | | f = 900 MHz | - | 0.09 | - | dB | |
| | | f = 1800 MHz | - | 0.10 | - | dB | |
| f = 2450 MHz | - | 0.12 | - | dB | | | |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------|--------------------------|---|-----|------|-----|---------|
| τ_L | charge carrier life time | when switched from $I_F = 10$ mA to $I_R = 6$ mA; $R_L = 100$ Ω ; measured at $I_R = 3$ mA | - | 0.55 | - | μ s |
| L_S | series inductance | $I_F = 100$ mA; $f = 100$ MHz | - | 0.4 | - | nH |

8 Graphical data



9 Package outline

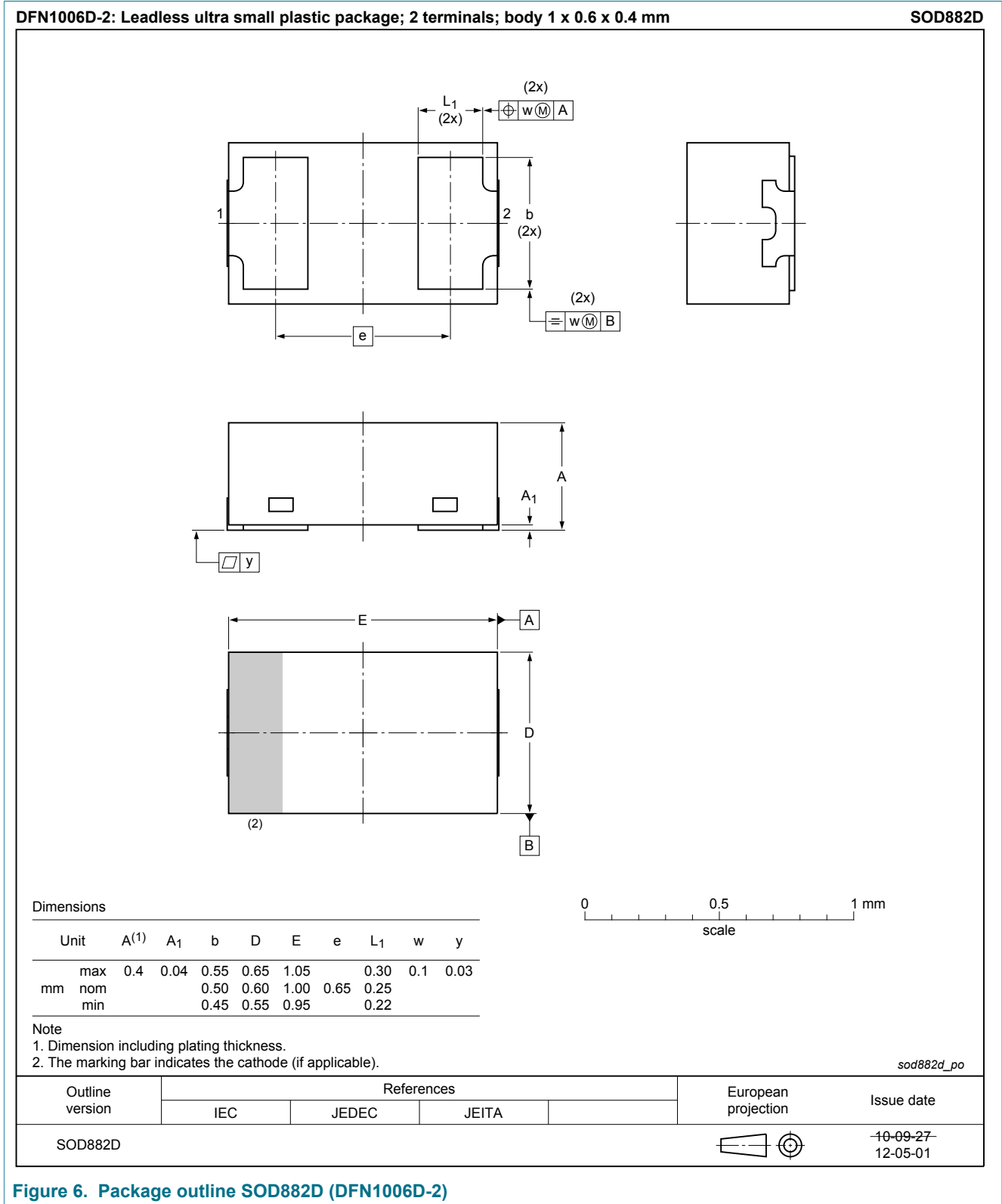


Figure 6. Package outline SOD882D (DFN1006D-2)

10 Abbreviations

Table 7. Abbreviations

| Acronym | Description |
|---------|---------------------------|
| PIN | P-type, intrinsic, N-type |
| SMD | surface-mounted device |
| RF | radio frequency |

11 Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|--------------------|---------------|-------------|
| BAP51LX v.3 | 20181126 | Product data sheet | - | BAP51LX v.2 |
| Modifications: | <ul style="list-style-type: none">• Section 1.2 "Features and benefits" has been updated.• The "Legal information" pages have been updated. | | | |
| BAP51LX v.2 | 20130806 | Product data sheet | - | BAP51LX v.1 |
| BAP51LX v.1 | 20070626 | Product data sheet | - | - |

12 Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors. In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without

notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products. NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Suitability for use in automotive applications — This NXP Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected

to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

| | | |
|-----------|---------------------------------------|----------|
| 1 | Product profile | 1 |
| 1.1 | General description | 1 |
| 1.2 | Features and benefits | 1 |
| 1.3 | Applications | 1 |
| 2 | Pinning information | 2 |
| 3 | Ordering information | 2 |
| 4 | Marking code | 2 |
| 4.1 | Binary marking code description | 2 |
| 5 | Limiting values | 3 |
| 6 | Thermal characteristics | 3 |
| 7 | Characteristics | 4 |
| 8 | Graphical data | 6 |
| 9 | Package outline | 7 |
| 10 | Abbreviations | 8 |
| 11 | Revision history | 8 |
| 12 | Legal information | 9 |

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2019.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 26 November 2018
Document identifier: BAP51LX

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[NXP:](#)

[BAP51LX,315](#)